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Effects of Processing Strategies and La+Sm Co-Doping on the Thermoelectric Performance of A-Site-Deficient SrTiO_{3-δ} Ceramics

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Abstract: The effect of calcining in either air (VSTO-A) or 5% H₂/N₂ (VSTO-H) on the thermoelectric performance of La and Sm co-doped A-site-deficient Sr_{1-3x/2}La_{x/2}Sm_{x/2}TiO_{3-δ} ceramics is reported. All calcined powders were sintered 6 h in 5% H₂/N₂ at 1773 K to ≥96% relative density. All peaks in X-ray diffraction patterns indexed as a cubic perovskite phase. Scanning electron microscopy revealed grain sizes ~14 and ~10 μm for VSTO-A and VSTO-H ceramics, respectively. x = 0.30 showed the lowest *k* (2.99 W/m.K at 973 K) for VSTO-A, whereas x = 0.20 had the lowest (2.67 W/m. K at 973 K) for the VSTO-H ceramics. x = 0.30 VSTO-A showed a thermoelectric figure of merit, ZT = 0.25 (at 973 K), whereas the maximum ZT = 0.30 (at 973 K) was achieved for x = 0.20 VSTO-H ceramics, demonstrating that thermoelectric properties are optimized when all processing is carried out in 5% H₂/N₂.

Keywords: thermoelectrics; solid-state reaction; particle size; grain structure; thermal conductivity

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1. Introduction

Many thermoelectric materials are being explored for power generation applications, such as GeTe [1], PbTe [2], half Heuslers [3], Bi₂Te₃ [4], and silicides [5]. These non-oxide materials are the most researched thermoelectric materials because they possess improved thermoelectric, intrinsic small phonon group velocity and low thermal conductivity *k* required to optimize the figure of merit, ZT [6]. However, most non-oxide materials, e.g., Bi₂Te₃, Sb₂Te₃, SiGe, and PbTe are toxic, scarce, and costly, and many have low operational temperature range; hence, they exhibit restricted applications [7]. Studies have shown that oxides are viable alternatives in surmounting some of the challenges associated with non-oxides [8,9]. Promising among these oxide materials are *p*-type layered cobaltates such as NaCo₂O₄, (Sr,Ca)₃Co₄O₉, Bi_{2-x}Pb_xCo₂O₈ (0 ≤ x ≤ 0.4), Tl_{0.4}[Sr_{0.9}O]_{1.12}CoO₂, and [Pb_{0.7}Hg_{0.4}Sr_{1.9}Co_{0.2}][CoO₂]_{1.8}, whose ZT values range between 0.8 and 1.0 from 800 to 1000 K [10]. In contrast, *n*-type have low ZT values compared to *p*-type oxides, with some of the best properties demonstrated by Al-Ga co-doped ZnO (0.47 at 1000 K and 0.65 at 1247 K, respectively) [11,12] and 10 mol% La and 10 mol% Nb co-doped SrTiO₃ and (ZT ≥ 0.60 at 1000–1100 K) [13].

Reduced rare earth (RE)-doped SrTiO_{3-δ} ceramics have also shown promising thermoelectric properties and have been extensively studied with different dopants and doping mechanisms, various processing conditions, the integration of graphene or graphene oxide or metals [14–19] and the intentional creation of secondary phases [20] to improve

the thermoelectric properties. Incorporation of graphene in oxide thermoelectrics is also a novel approach in achieving high ZT. Lin et al. [14] used this strategy by incorporating graphene in La-doped SrTiO₃. They achieved a maximum ZT value of 0.42 at room temperature for the composite with 0.6 wt.% graphene. Recently, an optimum ZT~1.42 (at 1050 K) was reported for Nb-doped SrTiO₃ with an incorporation of 0.5 wt.% natural graphite [19]. No doubt, this approach has opened up a new window for the fabrication of high-temperature thermoelectric generators.

The A-site vacancy effect has been studied in depth in our previous work [21] in which La-doped A-site-deficient Sr_{1-3x/2}La_xTiO₃ ceramics were processed in 5% H₂/N₂ reduced atmosphere, and a ZT = 0.41 (at 973 K) for x = 0.15 was achieved. Generally, introduction of cation vacancies in A- and/or B-site and doping with rare earth or transition metal cations followed by processing in a reduced atmosphere is a promising route to optimise thermoelectric properties [22]. In this study, the synergistic effects of the presence of Sr-(A-site) vacancies and processing conditions on the thermoelectric performance of Sr_{1-3x/2}La_{x/2}Sm_{x/2}TiO_{3-δ} (0.05 ≤ x ≤ 0.30) ceramics calcined in air (VSTO-A) and 5% H₂/N₂ (VSTO-H), with both sintered in reducing atmosphere, are examined.

2. Materials and Methods

A solid-state reaction (SSR) method was applied to synthesize A-site-deficient Sr_{1-3x/2}La_{x/2}Sm_{x/2}TiO₃ (x = 0.05, 0.10, 0.15, 0.20, 0.30) powders. SrCO₃ (99.9% purity) was dried at 180 °C overnight, and La₂O₃, Sm₂O₃, and TiO₂ (99.9% purity) were heated at 900 °C for 6 h to remove OH⁻ ions before weighing to ensure the correct stoichiometry. After drying, they were batched and mixed via ball milling (driver roller speed = 300 rpm) in isopropanol with yttria-stabilized zirconia (YSZ) milling media for 24 h. The obtained slurry was then dried at 80 °C and sieved using a 250 μm mesh. The dry mixture was calcined at 1573 K in air (VSTO-A) or in 5% H₂/N₂ mixed gas (VSTO-H) for 6 h and later re-milled using a ball mill at driver roller speed of 300 rpm. Particle size analysis (PSA) of the milled powders was performed using a Mastersizer 3000 Laser Particle Size Analyzer (Malvern Instruments Limited, UK). Finally, the calcined powders were pressed into pellets (20 mm in diameter and 2 mm thick) using a uniaxial press at 32 MPa for ~60 s. They were then sintering in flowing 5% H₂/N₂ gas at 1773 K for 6 h.

The experimental density of the ceramics was determined by the Archimedes' method using an electronic digital density balance (Mettler-Toledo AG Balance, Columbus, OH, USA). Thermogravimetric analysis (TGA) was performed using a Perkin Elmer Pyris 1 TGA Analyzer in air with a 5 °C/min heating rate up to 1000 °C followed by a 5 °C/min cooling rate to room temperature. The phase purity and lattice parameters of the ceramics were characterised by powder X-ray diffraction (XRD) with Cu Kα radiation (λ = 1.5406 Å) using a D2 phase diffractometer. Samples for scanning electron microscopy (Philips XL 30 S-FEG, Amsterdam, The Netherlands) were polished to a mirror finish, thermally etched, and carbon coated using an Edwards vacuum carbon coater (Edwards High Vacuum Ltd, England). After carbon coating of the samples, microstructural examination was performed using XL 30 S-FEG (Philips/FEI) at an accelerating voltage of 5–20 kV. The grain size in the microstructures was calculated using the line-intercept method [23,24].

The electrical conductivity (σ) and Seebeck coefficient (S) were simultaneously measured on ~15 mm × 2.5 mm × 3.5 mm bar samples as a function of temperature from 573–973 K in an Ar atmosphere using the four-probe method on a Netzsch SBA 458 Nemesis system. Thermal conductivity (k) of the ceramics was determined from experimental density, with specific heat and thermal diffusivity measured in a nitrogen atmosphere by the laser flash method (Anter Flashline™ 3000 Thermal Properties Analyzer)

3. Results and Discussion

3.1. Particle Size

The particle size distribution analysis of the calcined, doped SrTiO₃ powders after ball milling (before sintering) is presented in Table 1. All milled powders showed d₅₀ (median) particle sizes of 5.2 and 3.6 μm for VSTO-A and VSTO-H ceramics, respectively. Due to the same ball-milling parameters, calcination at the same temperature in 5% H₂/N₂ gas may be advantageous for achieving a lower average particle size for sintering.

Table 1. Particle size analysis of calcined La+Sm co-doped SrTiO₃ powders after 24 h ball milling.

Composition	x	Particle diameter (μm)		
		d ₁₀	d ₅₀	d ₉₀
Sr _{1-3x/2} La _{x/2} TiO ₃ (VSTO-A)	0.05	2.2	4.9	12.4
	0.10	2.4	5.0	9.8
	0.15	2.7	5.6	10.7
	0.20	2.9	6.0	11.5
	0.30	2.0	4.3	10.4
Sr _{1-3x/2} La _{x/2} TiO ₃ (VSTO-H)	0.05	1.6	3.6	7.8
	0.10	1.0	2.4	11.9
	0.15	1.6	3.3	7.6
	0.20	2.1	4.7	10.8
	0.30	1.8	3.9	9.8

3.2. Crystal and Grain Structure

XRD patterns for the crushed VSTO-A and VSTO-H ceramics are shown in Figure 1. All samples were single phase and indexed to the SrTiO₃ cubic perovskite structure with space group Pm-3m (PDF# 04-002-6890). The calculated lattice parameters and relative densities are shown in Table 2. The dopant (La+Sm) concentration dependence of the lattice parameters of VSTO-A and VSTO-H ceramics is presented in Figure 2. The density of all ceramics was measured by the Archimedes' method, and all samples have a relative density of ≥96% (Table 2).

The lattice parameters of VSTO-A ceramics decrease with increasing La+Sm concentrations. The lattice parameters of VSTO-A ceramics contract from 3.910 Å for x = 0.05 to a minimum value of 3.902 Å for x = 0.30, as shown in Figure 2. The shrinkage in lattice parameter is attributed to the smaller ionic radii of La³⁺ and Sm³⁺ (La³⁺ = 1.36 Å; Sm³⁺ = 1.24 Å in Coordination Number, CN 12) compared to that of Sr²⁺ (1.44 Å in CN 12) [21,25,26]. In contrast, the lattice parameters of VSTO-H ceramics for x = 0.05 to 0.20 increase with increasing La+Sm doping concentration, from 3.899 to 3.910 Å, before decreasing to 3.902 Å for x = 0.30. The lattice parameter increase may be due to a decrease in Coulombic Force in the lattice by the formation of oxygen vacancies accompanied by partial reduction of Ti⁴⁺ ions (0.605 Å for CN = 6) to the larger ionic radius Ti³⁺ ion (0.67 Å for CN = 6) [27]. The decrease in lattice parameter at high doping level (x = 0.30) may relate to exceeding the solid solution limit. However, due to the low volume fraction of secondary phase, which is difficult to detect by XRD, the results are inconclusive.

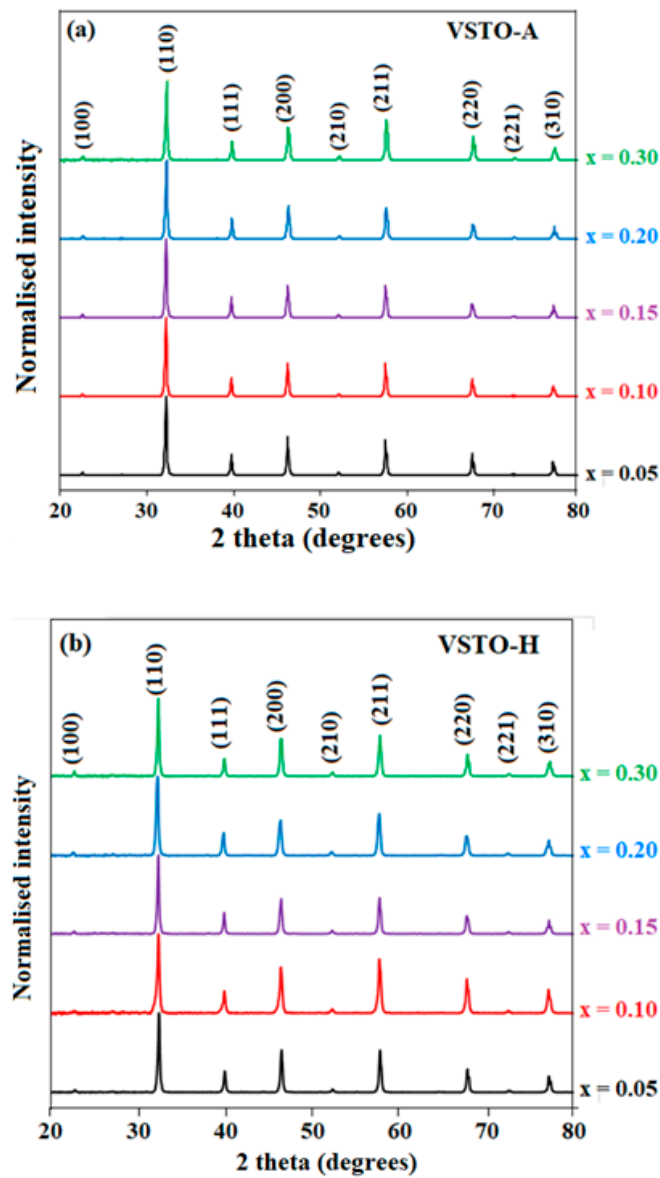


Figure 1. XRD patterns for (a) VSTO-A and (b) VSTO-H ceramics.

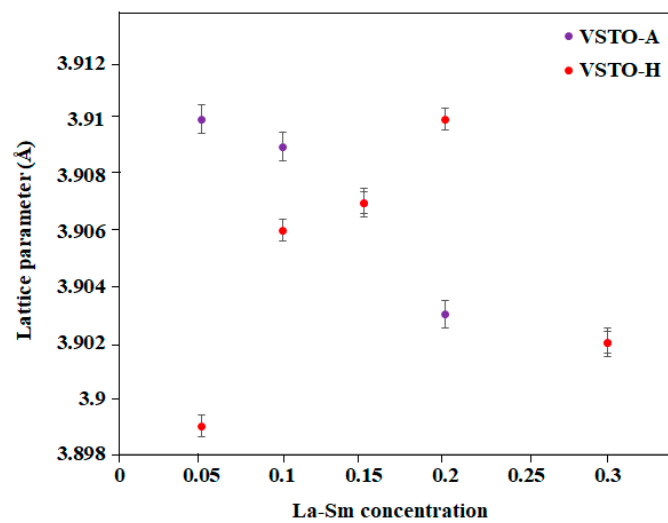


Figure 2. Dopant (La+Sm) concentration dependence of lattice parameters for VSTO-A and VSTO-H ceramics.

Table 2. Lattice parameters, cell volumes, and relative densities for (a) VSTO-A and (b) VSTO-H ceramics.

Composition	Lattice parameter (Å)	Cell volume (Å ³)	Relative density (%)
(a)			
0.05	3.91	59.776	98.4
0.10	3.909	59.736	98.9
0.15	3.907	59.639	98.2
0.20	3.903	59.456	98.4
0.30	3.902	59.41	98.9
(b)			
0.05	3.899	59.273	98.1
0.10	3.906	59.593	96.1
0.15	3.907	59.639	99.1
0.20	3.91	59.776	98.7
0.30	3.902	59.41	98.2

Scanning electron microscopy (SEM) micrographs of thermal etched surfaces for VSTO-A and VSTO-H ceramics are shown in Figure 3. All images revealed homogenous and dense microstructures, which agree with the high relative density of $\geq 96\%$ for the ceramics, as shown in Table 1. The average grain size of VSTO-A ceramics increased with increasing the dopant concentration from $5.1 \mu\text{m}$ for $x = 0.05$ to a maximum value of $15.3 \mu\text{m}$ for $x = 0.30$ ceramics. VSTO-H ceramics showed a similar trend to VSTO-A ceramics, but the grain sizes were smaller, especially at high x values, with $x = 0.30$ ceramics exhibiting a maximum size of $11.2 \mu\text{m}$. The small average grain size exhibited by VSTO-H ceramics compared to that of VSTO-A agrees with the particle size distribution (PSD) results reported in Table 2 for powders used for VSTO-A and VSTO-H ceramics. Thus, processing in a strongly reducing atmosphere (both for calcination and sintering) of vacancy co-doped $\text{Sr}_{1-3x/2}\text{La}_{x/2}\text{Sm}_{x/2}\text{TiO}_{3-\delta}$ ceramics contributes to smaller powder particle and ceramic grain sizes. This is in agreement with a study by Srivastava et al. [28] in which La-Nb co-doped SrTiO_3 ceramics sintered in air showed a grain size of $\sim 13 \mu\text{m}$ and $7\text{--}10 \mu\text{m}$ when sintered in a reducing atmosphere. Hence, the application of highly reducing conditions ($5\% \text{H}_2/\text{N}_2$) in both calcination and sintering is suggested to cause removal of a greater amount of oxygen, thereby generating a higher concentration of oxygen vacancies in the perovskite lattice. Although reduced grain size may contribute to a slight decrease in electrical conductivity, it shortens the mean free path (MFP) of the phonons, and more grain boundaries act as effective scattering centres, reducing k [29] with a consequent increase in ZT [30,31].

VSTO-A microstructures featured noticeable secondary phases (labelled with white circles), Figure 3a. The source of these features could not be ascertained but are assumed to be secondary phase(s) undetected by XRD due to their low volume fraction. The

secondary phases are more noticeable in $x = 0.30$ and may contribute to the low k observed in $x = 0.30$ ceramics (VSTO-A, see later).

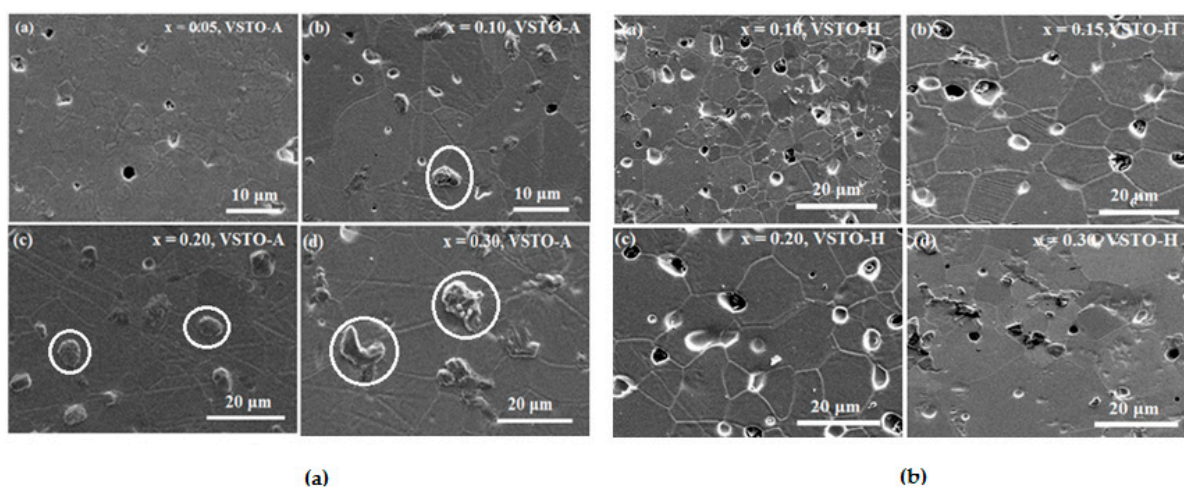


Figure 3. SEM micrographs for (a) VSTO-A and (b) VSTO-H ceramics.

3.3. Thermogravimetric Analysis

With increasing La+Sm concentration, the onset temperature for oxidation of the ceramics decreased with x , but oxygen uptake increased (Figure 4). $x = 0.05$ showed little oxidation in air up to 1000 °C. The colour of VSTO-A ceramics after TGA remained black for $x = 0.05$ and 0.10, whereas ceramics of $x = 0.15$ and 0.20 and $x = 0.30$ were brown and white, respectively. For VSTO-H ceramics, $x = 0.05$ remained black; however, $x = 0.10$, 0.15, 0.20, and 0.30 turned white after TGA. A black appearance signifies stability of the ceramics at high temperature, whereas white indicates significant oxidation has occurred. Variation in weight (and therefore oxidation) was larger for VSTO-H ceramics than VSTO-A ceramics (Figure 4) and is consistent with a higher level of reduction in VSTO-H due to the processing conditions. All ceramics (VSTO-A and VSTO-H) sintered in a reducing atmosphere were stable in air and resistant to oxidation until ~400 °C.

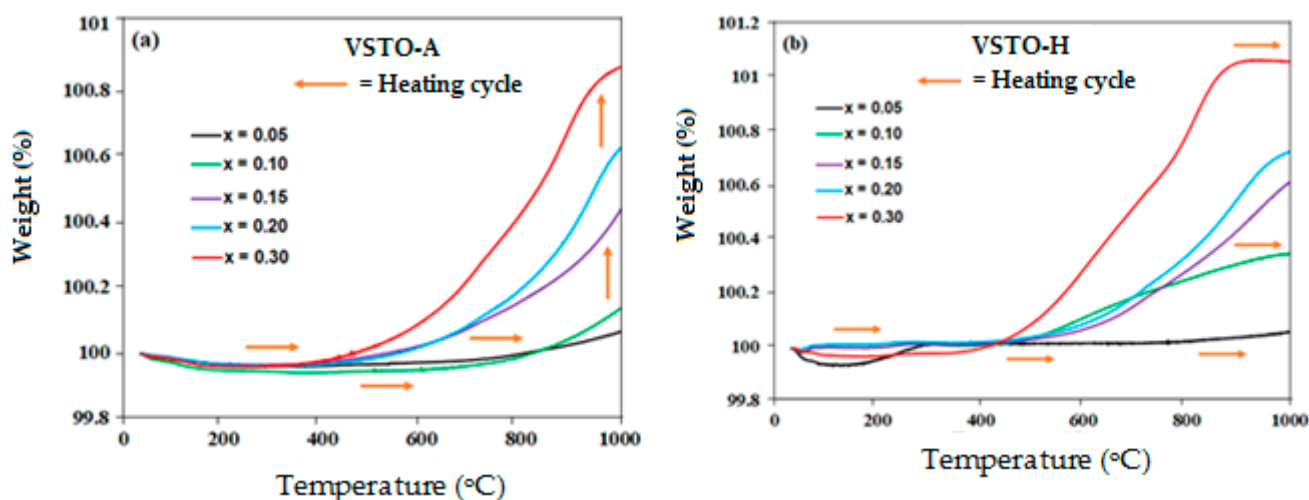


Figure 4. Thermogravimetric analysis showing the oxidation in air up to 1000 °C for (a) VSTO-A and (b) VSTO-H ceramics.

3.4. Thermoelectric Properties

3.4.1. VSTO-A Ceramics

The temperature dependence of the electrical conductivity, σ , for VSTO-A ceramics is shown in Figure 5a. σ of all VSTO-A ceramics decreases with increasing temperature over the measured temperature range, which confirms metallic behaviour. σ for $x = 0.05, 0.10, 0.15,$ and 0.20 ceramics increases with increasing La+Sm concentration, showing the dependence of σ on carrier concentration and mobility [32]. At $x = 0.30$, the electrical conductivity decreased. This drop may be related to secondary features observed in the SEM images and associated with the solid solution limit being exceeded or possibly a structural phase transition as a result of rotation of O-octahedra observed in RE-doped SrTiO₃ [21,33]. The highest σ obtained was 1184 S/cm at 573 K for $x = 0.20$. VSTO-A ceramics of higher concentrations ($x \geq 0.15$) showed enhanced σ when compared to that of Sr_{0.9}Nd_{0.1}TiO₃ with B₂O₃ and ZrO₂ additions [34] and La-Nb co-doped SrTiO₃ ceramics [13] in the same temperature range (573–973 K). The σ results show that A-site vacancies have a greater effect on conductivity than electronic compensation in La and Sm co-doped SrTiO₃ ($\sigma_{\max} = 942$ S/cm at 573 K for $x = 0.15$) [35]. This may relate to greater oxide ion diffusion rates through the vacated A-site, which permits a greater volume of reduced material (and therefore higher Ti³⁺ content) throughout the ceramic.

Seebeck coefficients of all VSTO-A ceramics are negative, indicating *n*-type behaviour, and confirm the electrons associated with mixed Ti^{3+(d¹)-Ti^{4+(d⁰)} are the dominant charge carriers. The absolute coefficient, $|S|$, for all compositions (Figure 5b) increases linearly with increasing temperature, showing metallic-type behaviour [25,26]. $|S|$ values decrease with increasing La+Sm concentration, which is consistent with an increase in σ , as shown in Figure 5a. $|S|$ of all samples at high temperature (973 K) fall within the range of 158–255 μ V/K, and these values exceed the minimum values of Seebeck coefficients (150–250 μ V/K) suggested for a good TE material [36].}

The temperature dependence of the power factor, PF, for the VSTO-A ceramics is presented in Figure 5c. $x \geq 0.15$ ceramics displayed a peak in behaviour between 573 and 673 K (Figure 5c), suggesting a semiconductor-like mechanism. Above 673 K, the power factors decreased with increasing temperature. For $x \leq 0.10$, the PF decreases over the measured temperature range, and a maximum PF value of ~ 1185 μ W/K² was obtained for $x = 0.10$ at 573 K. This high PF could be attributed to an optimised $|S|$ (125–193 μ V/K), which is higher than the $|S|$ values of all other compositions except $x = 0.05$. However, at high temperatures, PF of $x = 0.10$ decreased, possibly due to the lower σ (Figure 5a). The PF results obtained in this study are in agreement with most results in the literature for electron La-Yb [26] and La-Dy [37] co-doped SrTiO₃ ceramics but higher than the reported values for Nb-doped Sr_{0.95}La_{0.05}TiO₃ ceramics at high temperatures (≥ 973 K) [38].

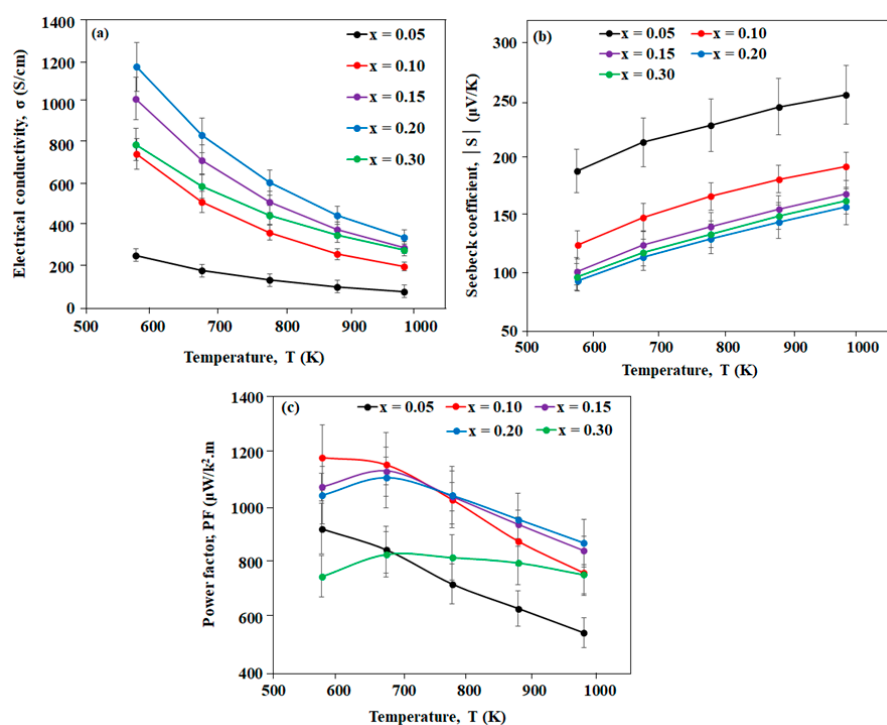


Figure 5. Temperature dependence of (a) electrical conductivity, σ ; (b) Seebeck coefficient, $|S|$; and (c) power factor, PF, for VSTO-A ceramics.

The temperature dependence of the total thermal conductivity (k) of VSTO-A ceramics is shown in Figure 6a. $x = 0.30$ ceramics exhibited the lowest k range (3.46–2.99 W/m.K with increasing temperature) over the measured temperature range, which suggests typical thermal conduction behaviour for a semiconductor [25] and control of lattice thermal conductivity k_L [26]. The low k values obtained for $x = 0.30$ could be attributed to the high concentration of secondary phases in the microstructure, which affected the thermal transport. Usually, a reduction of k in doped SrTiO_{3- δ} ceramics is ascribed to formation of oxygen vacancies in perovskites, preceded by sintering in a reducing atmosphere [33]. An increase in La+Sm concentration results in decreasing k_L , which indicates increasing lattice defects and shortening of the mean free path (MFP) of the phonons [21]. At the maximum temperature (973 K), the electronic contribution to the total thermal conductivity was estimated at an average of 0.0024 W/m using a Lorentz number (10^{-8} W Ω K $^{-2}$) for a non-degenerated semiconductor. This result shows the reduction in k mainly originates from the lattice vibrations (phonons); hence, k_L plays a dominant role in k . Thus, there is insignificant difference between the values of k and that of k_L .

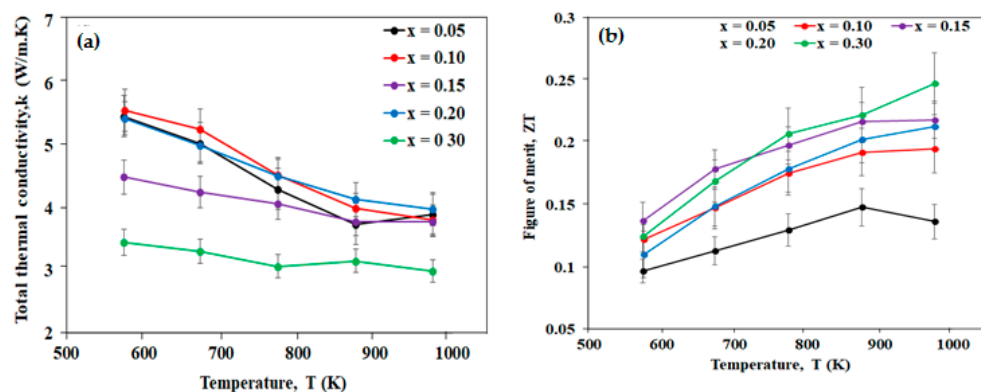


Figure 6. Temperature dependence of (a) total thermal conductivity, k , and (b) thermoelectric figure of merit, ZT, for VSTO-A ceramics.

The thermoelectric figure of merit, ZT , of all compositions generally increases with increasing temperature over the entire measured temperature range, as shown in Figure 6b. ZT for $x = 0.20$ – 0.30 increases over the measured temperature range, whereas ZT for $x \leq 0.15$ ceramics drops at 873 K. $x = 0.30$ ceramics recorded the highest ZT value of 0.25 at 973 K. The low k values observed for $x = 0.30$ ceramics result in higher ZT values, especially at high temperatures (773–973 K) despite its lower PF value.

3.4.2. VSTO-H Ceramics

The temperature dependence of σ for VSTO-H ceramics is shown in Figure 7a. The decrease of σ for all samples with increasing temperature is consistent with metallic conduction. σ increases with increasing La+Sm concentration, and a maximum value of 1023 S/cm at 573 K was obtained for $x = 0.30$. It is noteworthy that the processing atmosphere, either in air or 5% H_2/N_2 , has no significant effect on σ of VSTO-A and VSTO-H ceramics at higher temperatures but modifies the behaviour at lower temperatures. For example, in $x = 0.15$ ceramics, VSTO-A and VSTO-H showed σ values of 1029 and 758 S/cm, respectively at the lowest measured temperature (573 K). At the highest measured temperature (973 K), VSTO-A exhibited σ of 298 S/cm, and VSTO-H showed $\sigma = 284$ S/cm. This strongly suggests the bulk conductivity is the same for a given dopant level irrespective of processing atmosphere, whereas grain boundaries or electrical heterogeneities are responsible for the variations in lower temperature conductivity. Generally, the processing atmosphere showed little or no disparity on the electrical transport properties (σ , S , PF) of VSTO-A or VSTO-H ceramics. For example, $x = 0.15$ at 973 K showed PF values of 873 and 870 $\mu W/K^2 \cdot m$ for VSTO-A and VSTO-H ceramics, respectively (Figures 5c and 7c).

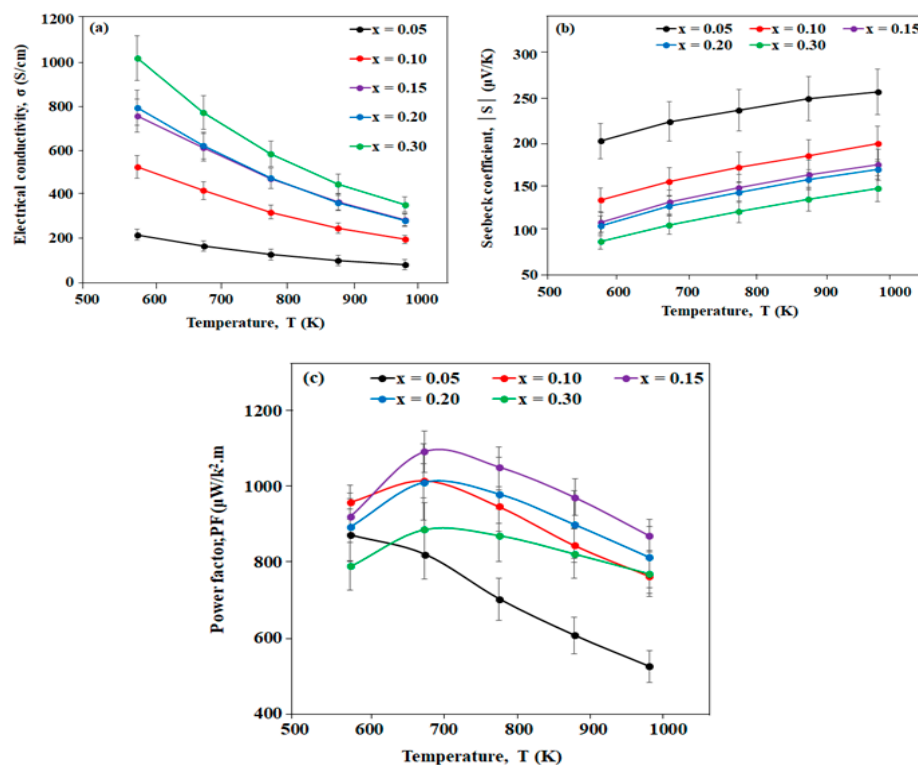


Figure 7. Temperature dependence of (a) electrical conductivity, σ ; (b) Seebeck coefficient, $|S|$; and (c) power factor, PF, for VSTO-H ceramics.

The effect of processing atmosphere was clearly observed in the thermal transport properties of the ceramics. The lowest k (2.67 W/m. K) at 973 K was observed in $x = 0.20$ (Figure 8a), which is ~11% lower than the lowest k (2.99 W/m. K at 973 K) obtained in VSTO-A ceramics. The k value range (3.25–2.67 W/m. K) observed in VSTO-H ceramics is

comparable to the lowest k values of most doped $\text{SrTiO}_{3-\delta}$ ceramics prepared via conventional methods [7,33]. This significant reduction in k as shown in VSTO-H compositions confirms that strongly reducing conditions are efficient in achieving low thermal conductivity in SSR-synthesized $\text{Sr}_{1-3x/2}\text{La}_{x/2}\text{Sm}_{x/2}\text{TiO}_{3-\delta}$ ceramics.

The overall effect of the electrical and thermal transport properties on the thermoelectric performance of VSTO-H ceramics is shown by the temperature dependence of ZT (Figure 8b). ZT of $x \geq 0.15$ ceramics increases with increasing dopant concentration. In contrast, ZT of $x \leq 0.10$ ceramics increases within the temperature range 573–873 K but decreases at high temperatures (973 K). $x = 0.20$ possesses the highest ZT over the entire measured temperature range, reaching a maximum value of 0.30 at 973 K.

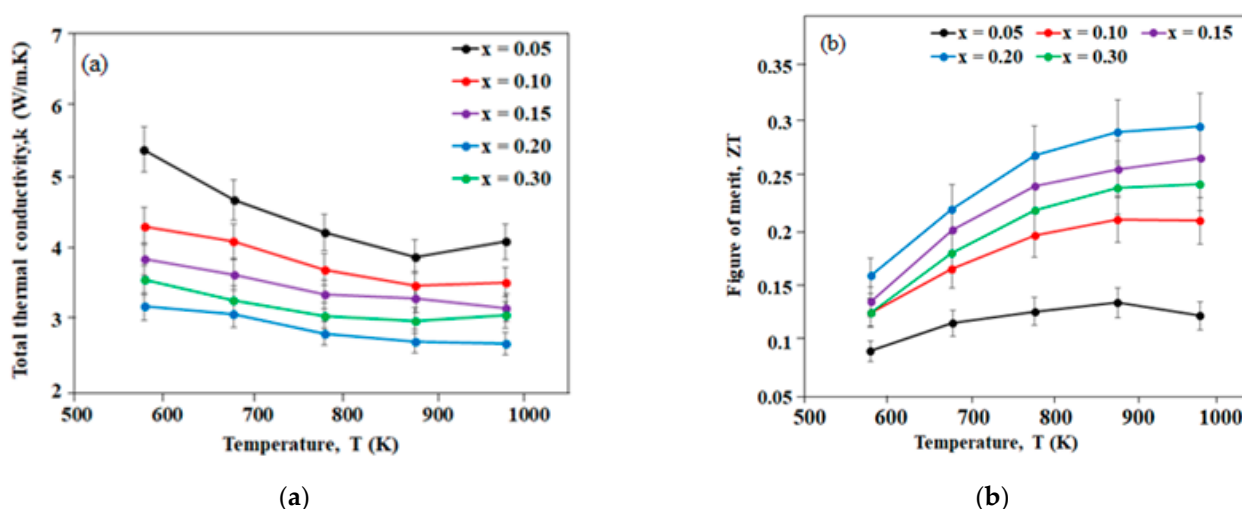


Figure 8. Temperature dependence of (a) total thermal conductivity, k , and (b) thermoelectric figure of merit, ZT, for VSTO-H ceramics.

4. Conclusions

A-site-deficient $\text{Sr}_{1-3x/2}\text{La}_{x/2}\text{Sm}_{x/2}\text{TiO}_{3-\delta}$ ($x = 0.05, 0.10, 0.15, 0.20,$ and 0.30) ceramics were successfully prepared by the solid-state reaction method. A portion were calcined in air (VSTO-A), whilst the remainder was calcined in 5% H_2/N_2 (VSTO-H), and both were sintered in 5% H_2/N_2 flowing gas at 1773 K for 6 h. Generally, Sr vacancies, La+Sm co-doping, and a highly reducing atmosphere decreased the thermal conductivity, with $\text{Sr}_{1-3x/2}\text{La}_{x/2}\text{Sm}_{x/2}\text{TiO}_{3-\delta}$ VSTO-H achieving 3.25–2.67 W/m.K over the entire measured temperature range. All ceramics (VSTO-A and VSTO-H) were resistant to oxidation in air up to ~ 400 °C.

In VSTO-A ceramics, $x = 0.30$ achieved a maximum ZT value of 0.25 at 973 K, and an improved ZT = 0.30 at 973 K was obtained for $x = 0.20$ VSTO-H ceramics. The higher ZT value achieved in VSTO-H ceramics reflects a balance between reduced k and good metallic σ behaviour without compromising the power factor. The application of a strongly reducing atmosphere in the processing of the ceramics (both in calcination and sintering, as seen for VSTO-H ceramics) provided a promising route to further enhance the thermoelectric properties of titanate-based ceramics.

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